

TinyLogic UHS Buffer with Three-State Output NC7SZ126

Description

The NC7SZ126 is a single buffer with three–State output from **onsemi**'s Ultra–High Speed (UHS) series of TinyLogic. The device is fabricated with advanced CMOS technology to achieve ultra–high speed with high output drive while maintaining low static power dissipation over a broad V_{CC} operating range. The device is specified to operate over the 1.65 V to 5.5 V V_{CC} operating range. The inputs and output are high impedance above ground when V_{CC} is 0 V. Inputs tolerate voltages up to 5.5 V independent of V_{CC} operating voltage. The output tolerates voltages above V_{CC} in the 3–STATE condition.

Features

- Ultra-High Speed: t_{PD} = 2.6 ns (Typical) into 50 pF at 5 V V_{CC}
- High Output Drive: ±24 mA at 3 V V_{CC}
- Broad V_{CC} Operating Range: 1.65 V to 5.5 V
- Matches Performance of LCX when Operated at 3.3 V V_{CC}
- Power Down High-Impedance Inputs / Outputs
- Over-Voltage Tolerance Inputs Facilitate 5 V to 3 V Translation
- Proprietary Noise / EMI Reduction Circuitry
- Ultra-Small MicroPakTM Packages
- Space-Saving SOT23-5, SC-74A and SC-88A Packages
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

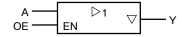
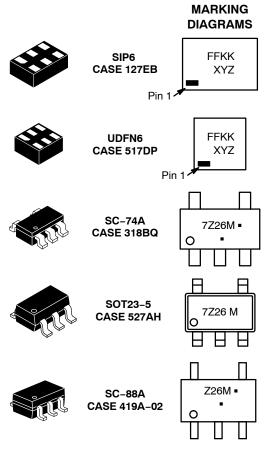


Figure 1. Logic Symbol



FF, 7Z26, Z26 = Specific Device Code

KK = 2-Digit Lot Run Traceability Code

XY = 2-Digit Date Code Format
Z = Assembly Plant Code

M = Date Code ■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 6 of this data sheet.

Pin Configurations

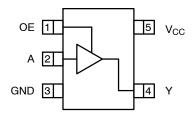


Figure 2. SOT23-5, SC-88A and SC-74A (Top View)

OE 1 6 V_{CC} A 2 5 NC GND 3 4 Y

Figure 3. MicroPak (Top Through View)

PIN DEFINITIONS

Pin # SOT23-5 / SC-88A / SC74A	Pin # MicroPak	Name	Description
1	1	OE	Input
2	2	Α	Input
3	3	GND	Ground
4	4	Υ	Output
5	6	V _{CC}	Supply Voltage
	5	NC	No Connect

FUNCTION TABLE

Inp	Output	
OE	Α	Υ
Н	L	L
Н	Н	Н
L	X	Z

H = HIGH Logic Level L = LOW Logic Level X = HIGH or LOW Logic Level Z = HIGH Impedance State

ABSOLUTE MAXIMUM RATINGS

Symbol	Param	eter	Min	Max	Unit
V _{CC}	Supply Voltage		-0.5	6.5	V
V _{IN}	DC Input Voltage		-0.5	6.5	V
V _{OUT}	DC Output Voltage		-0.5	6.5	V
I _{IK}	DC Input Diode Current	V _{IN} < 0 V	-	-50	mA
I _{OK}	DC Output Diode Current	V _{OUT} < 0 V	-	-50	mA
I _{OUT}	DC Output Current	•	-	±50	mA
I _{CC} or I _{GND}	DC V _{CC} or Ground Current	-	±50	mA	
T _{STG}	Storage Temperature Range		-65	+150	°C
TJ	Junction Temperature Under Bias		-	+150	°C
T _L	Junction Lead Temperature (Solo	lering, 10 Seconds)	-	+260	°C
P_{D}	Power Dissipation in Still Air	SC-74A / SOT23-5	-	390	mW
		SC-88A	-	332	
		MicroPak-6	-	812	1
		MicroPak2™-6	-	812	1
ESD	Human Body Model, JEDEC: JES	SD22-A114	-	2000	V
	Charge Device Model, JEDEC: J	ESD22-C101	-	1000	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	Supply Voltage Operating		1.65	5.5	V
	Supply Voltage Data Retention		1.5	5.5	
V _{IN}	Input Voltage		0	5.5	V
V _{OUT}	Output Voltage	Active State	0	V _{CC}	V
		Three-State	0	5.5	
T _A	Operating Temperature		-40	+85	°C
t _r , t _f	Input Rise and Fall Times	V _{CC} = 1.8 V, 2.5 V ±0.2 V	0	20	ns/V
		V _{CC} = 3.3 V ±0.3 V	0	10	
		V _{CC} = 5.0 V ±0.5 V	0	5	
$\theta_{\sf JA}$	Thermal Resistance	SC-74A / SOT23-5	-	320	°C/W
		SC-88A	-	377	
		MicroPak-6	-	154	1
		MicroPak2-6	-	154	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

1. Unused inputs must be held HIGH or LOW. They may not float.

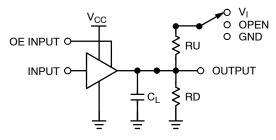
DC ELECTRICAL CHARACTERISTICS

				T	\ = +25°	°C	T _A = -40	to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit
V _{IH}	HIGH Level Input Voltage	1.65 to 1.95		0.65 V _{CC}	-	-	0.65 V _{CC}	-	V
		2.30 to 5.50		0.70 V _{CC}	-	-	0.70 V _{CC}	-	
V _{IL}	LOW Level Input Voltage	1.65 to 1.95		-	-	0.35 V _{CC}	-	0.35 V _{CC}	V
		2.30 to 5.50		-	-	0.30 V _{CC}	-	0.30 V _{CC}	1
V _{OH}	HIGH Level Output Voltage	1.65	$V_{IN} = V_{IH}$ or V_{IL} ,	1.55	1.65	-	1.55	-	V
		1.80	I _{OH} = -100 μA	1.70	1.80	-	1.70	-	
		2.30		2.20	2.30	-	2.20	-	1
		3.00		2.90	3.00	-	2.90	-	1
		4.50		4.40	4.50	-	4.40	-	1
		1.65	I _{OH} = -4 mA	1.29	1.52	-	1.29	-	
		2.30	I _{OH} = -8 mA	1.90	2.15	-	1.90	-	
		3.00	I _{OH} = -16 mA	2.40	2.80	-	2.40	-	
		3.00	I _{OH} = -24 mA	2.30	2.68	-	2.30	-	1
		4.50	I _{OH} = -32 mA	3.80	4.20	-	3.80	-	1
V _{OL}	LOW Level Output Voltage	1.65	$V_{IN} = V_{IH}$ or V_{IL} ,	-	0.00	0.10	-	0.10	V
		1.80 I _{OL} = 100 μ	I _{OL} = 100 μA	_	0.00	0.10	-	0.10	1
		2.30		-	0.00	0.10	-	0.10	
		3.00		_	0.00	0.10	_	0.10	
		4.50		_	0.00	0.10	_	0.10	1
		1.65	I _{OL} = 4 mA	_	0.80	0.24	_	0.24	1
		2.30	I _{OL} = 8 mA	-	0.10	0.30	-	0.30	1
		3.00	I _{OL} = 16 mA	_	0.15	0.40	_	0.40	1
		3.00	I _{OL} = 24 mA	-	0.22	0.55	-	0.55	1
		4.50	I _{OL} = 32 mA	-	0.22	0.55	-	0.55	1
I _{IN}	Input Leakage Current	1.65 to 5.5	V _{IN} = 5.5 V, GND	-	_	±1	-	±10	μА
I _{OZ}	3-STATE Output Leakage	1.65 to 5.5	$V_{IN} = V_{IH}$ or V_{IL} $V_O = V_{CC}$ or GND	-	-	±1	-	±10	μΑ
l _{OFF}	Power Off Leakage Current	0	V _{IN} or V _{OUT} = 5.5 V	_	-	1	-	10	μΑ
I _{CC}	Quiescent Supply Current	1.65 to 5.50	V _{IN} = 5.5 V, GND	-	_	2	-	20	μΑ

AC ELECTRICAL CHARACTERISTICS

				-	Γ _A = +25°0	;	T _A = -40	to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit
t _{PLH} , t _{PHL}	Propagation Delay (Figure 4, 6)	1.65	C _L = 15 pF,	-	6.4	13.2	-	13.8	ns
		1.80	$R_D = 1 M\Omega$ $S_1 = OPEN$	-	5.3	11.0	-	11.5	
		2.50 ±0.20]	-	3.4	7.5	-	8.0	
		3.30 ±0.30]	-	2.5	5.2	-	5.5	
		5.00 ±0.50	1	-	2.1	4.5	-	4.8	
		3.30 ±0.30		-	3.2	5.7	-	6.0	
		5.00 ±0.50	$R_D = 500 \Omega$ $S_1 = OPEN$	-	2.6	5.0	-	5.3	
t _{PZL} , t _{PZH}	Output Enable Time	1.65	C _L = 50 pF,	-	8.4	15.0	-	15.6	ns
	(Figure 4, 6)	1.80	$R_D = 500 \Omega$ $RU = 500 \Omega$	-	6.1	11.5	-	12.0	
		2.50 ±0.20	$S_1 = GND \text{ for } t_{PZH}$ $S_1 = V_{IN} \text{ for } t_{PZL}$	-	3.8	8.0	-	8.5	
		3.30 ±0.30	$V_{IN} = 2 \cdot V_{CC}$	-	3.2	5.7	-	6.0	
		5.00 ±0.50		-	2.3	5.0	-	5.3	
t _{PLZ} , t _{PHZ}	Output Disable Time	1.65	C _L = 50 pF,	-	6.5	13.2	-	14.5	
	(Figure 4, 6)	1.80	$R_D = 500 \Omega$ RU = 500 Ω	_	5.6	11.0	-	12	
		2.50 ±0.20	$S_1 = GND \text{ for } t_{PHZ}$ $S_1 = V_{IN} \text{ for } t_{PLZ}$	_	4.0	8.0	-	8.5	
		3.30 ±0.30	$V_{IN} = 2 \cdot V_{CC}$	_	3.5	5.7	-	6.0	
		5.00 ±0.50]	_	2.5	4.7	-	5.0	
C _{IN}	Input Capacitance	0.00		-	4	-	-	-	pF
C _{OUT}	Output Capacitance	0.00		ı	8	-	-	_	pF
C _{PD}	Power Dissipation Capacitance	3.30		ı	17	-	-	-	pF
	(Note 2) (Figure 5)	5.00		-	24	_	-	-	

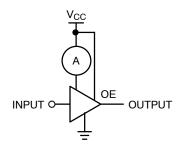
^{2.} C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. C_{PD} is related to I_{CCD} dynamic operating current by the expression: I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CC}static).



NOTE:

3. C_L includes load and stray capacitance; Input PRR = 1.0 MHz; t_W = 500 ns

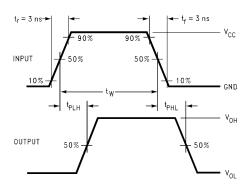
Figure 4. AC Test Circuit



NOTE:

4. Input = AC Waveform; $t_r = t_f = 1.8$ ns; PRR = 10 MHz; Duty Cycle = 50%.

Figure 5. I_{CCD} Test Circuit



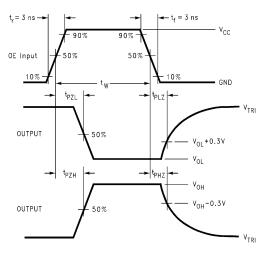


Figure 6. AC Waveforms

ORDERING INFORMATION

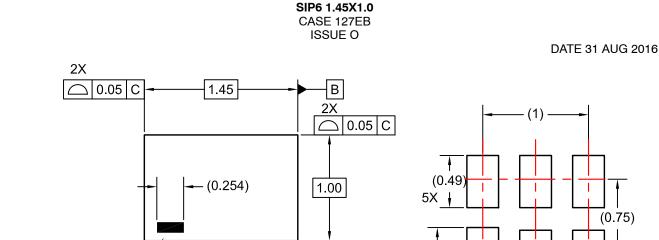
Part Number	Top Mark	Packages	Shipping [†]
NC7SZ126M5X	7Z26	SC-74A	3000 / Tape & Reel
NC7SZ126M5X-L22090	7Z26	SOT23-5	3000 / Tape & Reel
NC7SZ126P5X	Z26	SC-88A	3000 / Tape & Reel
NC7SZ126P5X-F22057	Z26	SC-88A	3000 / Tape & Reel
NC7SZ126L6X	FF	SIP6, MicroPak	5000 / Tape & Reel
NC7SZ126L6X-L22175	FF	SIP6, MicroPak	5000 / Tape & Reel
NC7SZ126FHX	FF	UDFN6, MicroPak2	5000 / Tape & Reel
NC7SZ126FHX-L22175	FF	UDFN6, MicroPak2	5000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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PIN 1 IDENTIFIER

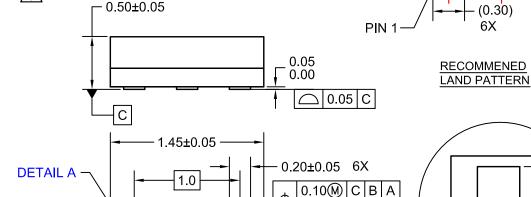
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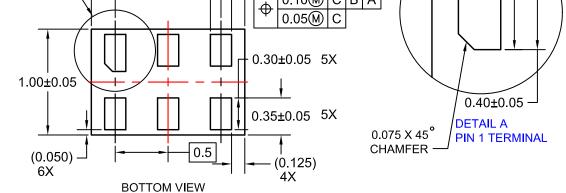
Α

(0.52)

1X <u>1</u>



TOP VIEW



NOTES:

- 1. CONFORMS TO JEDEC STANDARD MO-252 VARIATION UAAD
- 2. DIMENSIONS ARE IN MILLIMETERS
- 3. DRAWING CONFORMS TO ASME Y14.5M-2009
 4. PIN ONE IDENTIFIER IS 2X LENGTH OF ANY
- - OTHER LINE IN THE MARK CODE LAYOUT.

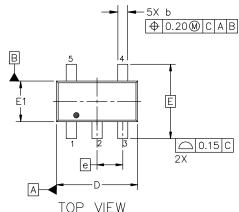
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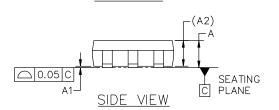
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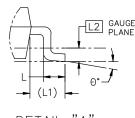


SC-74A-5 3.00x1.50x0.95, 0.95P CASE 318BQ ISSUE C

DATE 26 FEB 2024







DETAIL "A"
SCALE 2:1

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present. Some products may not follow the Generic Marking.

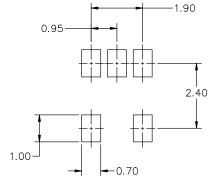
NOTES:

- DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
- 2. ALL DIMENSION ARE IN MILLIMETERS (ANGLES IN DEGREES).
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS.
 MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF
 BASE MATERIAL.
- 4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OF GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE.

DETAIL	A —
r° f	
END	VIEW

DIM				
DIIVI	MIN.	NOM.	MAX.	
А	0.90	1.00	1.10	
A1	0.01	0.18	0.10	
A2	(0.95 REF		
Ф	0.25	0.37	0.50	
С	0.10	0.18	0.26	
D	2.85	3.00	3.15	
Е	:	2.75 BSC	;	
E1	1.35	1.50	1.65	
е	(0.95 BSC	;	
L	0.20	0.40	0.60	
L1	0.62 REF.			
L2	0.25 BSC			
Θ	0.	5*	10°	

MILLIMETERS



RECOMMENDED MOUNTING FOOTPRINT*

* FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

DOCUMENT NUMBER:	98AON66279G	Electronic versions are uncontrolled except when accessed directly from the Documen Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	SC-74A-5 3.00x1.50x0.95.	0.95P	PAGE 1 OF 1

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SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE M

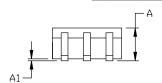
DATE 11 APR 2023

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETERS
- 419A-01 DBSDLETE. NEW STANDARD 419A-02
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

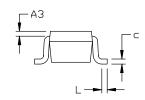
DIM	MILLIMETERS			
الملتط	MIN.	N□M.	MAX.	
А	0.80	0.95	1.10	
A1			0.10	
A3	0,20 REF			
b	0.10	0.20	0.30	
С	0.10		0.25	
D	1.80	2.00	2,20	
Е	2.00	2.10	2.20	
E1	1.15	1.25	1.35	
е	0.65 BSC			
L	0.10	0.15	0.30	

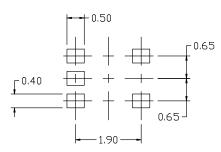
е Ε1 0



5X b

◆ 0.2 M B M





RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

STYLE 9:

STYLE '	1:
PIN 1.	BASE
2.	EMITTER
3.	BASE
4.	COLLECTOR
5.	COLLECTOR

STYLE 2: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR CATHODE

STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1 STYLE 8:

PIN 1. CATHODE 2. COLLECTOR 3. N/C

4. BASE

STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3 SOURCE 1 4. GATE 1 5. GATE 2

PIN 1. ANODE 2. CATHODE

3. ANODE 4. ANODE

STYLE 5: PIN 1. CATHODE 2. COMMON ANODE 3. CATHODE 2 4. CATHODE 3 5. CATHODE 4

Note: Please refer to datasheet for style callout. If style type is not called

out in the datasheet refer to the device

٥.	
4.	COLLECTOR
5.	COLLECTOR 2

DOCUMENT NUMBER:

2. BASE 2

STYLE 6:

PIN 1. EMITTER 2 2. EMITTER 3. BASE 4. COLLECTOR /BASE 1 5. COLLECTOR

STYLE 7:

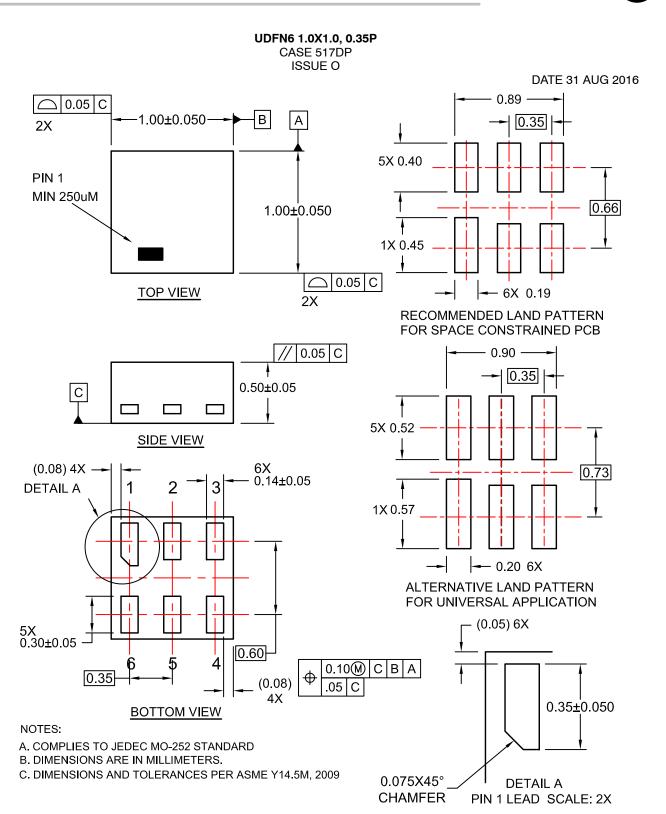
PIN 1. BASE

98ASB42984B

 ANODE
 ANODE datasheet pinout or pin assignment. 5. EMITTER Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.

DESCRIPTION: SC-88A (SC-70-5/SOT-353) **PAGE 1 OF 1**

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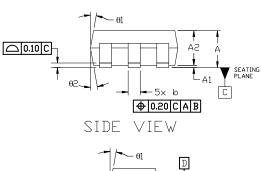
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В

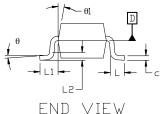


NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 19894
- CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS, MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.25 PER SIDE. D AND E1 DIMENSIONS ARE DETERMINED AT DATUM D.
- DIMENSION 'b' DOES NOT INCLUDE DAMBAR PROTRUSION. DAMBAR PROTRUSION SHALL BE O. 08mm TOTAL IN EXCESS OF THE 'b' DIMENSION AT MAXIMUM MATERIAL CONDITION. MINIMUM SPACE BETWEEN PROTRUSION AND AN ADJACENT LEAD SHALL NOT BE LESS THAN 0.07mm.



TOP VIEW



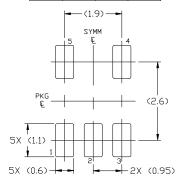
GENERIC MARKING DIAGRAM*



XXX = Specific Device Code = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may not follow the Generic Marking.

	MILLIMETERS		
DIM	MIN.	N□M.	MAX.
Α	0.90		1.45
A1	0.00	_	0.15
A2	0.90	1.15	1.30
b	0.30	_	0.50
_	0.08	_	0.22
D	2.90 BSC		
Ε	2.80 BSC		
E1	1.60 BSC		
е	0.95 BSC		
L	0.30	0.45	0.60
L1	0.60 REF		
L2	0.25 REF		
θ	0°	4°	8°
θ1	0°	10°	15°
θ2	0°	10°	15°



RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the $\square N$ Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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